Supplementary Information for:

Synthesis and Near-infrared Fluorescence of K₅NdLi₂F₁₀

Nanocrystals and Its Dispersion with High Doping

Concentration and Long Lifetime

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S1. Fitting curve of refractive index



Figure S1. fitting curve of refractive index for $K_5NdLi_2F_{10}$ nanocrystals dispersion in PEG400

Figure S1 shows the fitting curve of refractive index for $K_5NdLi_2F_{10}$ nanocrystals dispersion in PEG-400, which was measured on WYV-V-prismrefractometer. The

experimental data was analyzed by soft of MATrix LABoratory. We could get the refractive index at 1048 nm was 1.4579.

S2. Judd-Ofelt calculation

Based on the absorption spectrum which was shown in the inset picture of Figure 7, there are five transitions corresponding to transitions from ${}^{4}I_{9/2}$ ground state manifold to various excited states. The experimental oscillator strengths (f_{exp}) of each electronic transition of Nd³⁺ can be evaluated by the following Equation S1¹:

$$f_{\exp} = \frac{mc^2}{\pi e^2 N \lambda^2} \int \alpha(\lambda) d\lambda$$
 (1)

Where *m* and *e* are electron mass and charge, *c* is the velocity of light, *N* is the number density of Nd³⁺ ions, and α (λ) is the absorption coefficient. According to Judd–Ofelt theory, the calculated oscillator strengths (f_{cal}) of electronic transitions from the ground state (*aJ*) level to the excited state (*bJ'*) level are given by the Equation S2²:

$$f_{cal}(aJ,bJ') = \frac{8\pi^2 mc}{3h\lambda(2J+1)} \frac{(n^2+2)^2}{9n} \sum_{t=2,4,6} \Omega_t \left| \left\langle aJ \right| U^{(t)} \right| \left| bJ' \right\rangle \right|^2$$
(2)

Where *n* is the refractive index of the host, *h* is the Planck constant, 2J+1 is the degeneracy of the ground state. $|\langle aJ || U(t) || bJ' \rangle|^2$ represents the reduced matrix elements that are insensitive to the local environment, and those values for Nd³⁺ ions given by *Carnall et al* were used in the calculations^[3,4]. The values of three Judd-Ofelt parameters $\Omega_{t}_{(2, 4, 6)}$ were provided by a least-squares fitting of f_{exp} to f_{cal} . According to the Judd-Ofelt formulae described, measured oscillator strengths (f_{exp}), calculated

oscillator strengths (f_{cal}) and Judd-Ofelt parameters Ω_t of K₅NdLi₂F₁₀ nanocrystals

were determined (Listed in Table S1).

Table S1. Observed absorption peak positions, integrated absorption coefficient, measured oscillator strengths (f_{exp}), calculated oscillator strengths (f_{cal}) and Judd-Ofelt parameters of the K₅NdLi₂F₁₀ nanocrystal dispersion ^a.

| Electronic transition | Absorption peak | Absorption coefficient | Oscillator strength | Oscillator strength |
|---|-----------------|----------------------------|---------------------------------|--|
| (from ⁴ l _{9/2}) | (nm) | ∫α(λ)dλ(10 ⁻⁷) | $f_{exp}(10^{-6} \text{ cm}^2)$ | <i>f_{cal}</i> (10 ⁻⁶ cm ²) |
| ${}^{4}G_{7/2} {+}^{4}G_{9/2} {+}^{2}K_{13/2}$ | 521 | 14.20691 | 4.55085 | 4.45444 |
| ${}^{4}G_{5/2} + {}^{2}G_{7/2}$ | 576 | 19.46721 | 5.10968 | 6.70554 |
| ⁴ F _{7/2} + ⁴ S _{3/2} | 743 | 23.68136 | 3.73563 | 4.27054 |
| ⁴ F _{5/2} + ⁴ H _{9/2} | 800 | 24.98455 | 3.39959 | 5.33955 |
| ⁴ F _{3/2} | 866 | 17.88561 | 2.07492 | 2.56509 |
| Ω_2 (×10 ⁻²⁰ cm ²) | | 1 | 1.153 | |
| $\Omega_4 \; (\times 10^{-20} \; cm^2)$ | 6.174 | | | |
| Ω_{6} (×10 ⁻²⁰ cm ²) | | 2 | 2.997 | |

^a Based on absorption data from K₅NdLi₂F₁₀.

From the Judd–Ofelt parameters Ω_t obtained above, the radiative transition rates for electronic dipole transitions between an excited state and the lower lying levels can be calculated by the following Equation S3 ⁵:

$$A(aJ, bJ') = \frac{64\pi^4 e^2 n^2 \chi}{3h\lambda^3 (2J+1)} \sum_{t=2,4,6} \Omega_t \left| \left\langle 4f^N aJ \right| U^{(t)} \left| 4f^N bJ' \right\rangle \right|^2$$
(3)

The radiative lifetime of the ${}^{4}F_{3/2}$ state is related to the radiative decay rate through following Equation S4 ⁶:

$$\tau_{r}(a) = \frac{1}{A_{ed}(a)} = \frac{1}{\sum_{b} A_{ed}(ab)}$$
(4)

The quantum efficiency (ϕ) of the emission bands can be evaluated from the

following Equation S5⁷:

$$\varphi = \frac{\tau_{mea}}{\tau_{rad}} \tag{5}$$

The emission spectra of K_5 NdLi₂F₁₀ nanocrystals in PEG-400 shows three emission bands centered at 865, 1048, and 1332 nm. The fluorescence branching ratios of these bands, radiative transition probability (A_{rad}) between the excited states, and radiative lifetime of an emitting state were presented in Table S2.

Table S2. Observed emission bands, their measured and calculated radiative properties of $K_5 NdLi_2 F_{10}\,^a$

| 5 2 10 | | | | |
|---|-----------------|-------------------|-------------------|-----------------------|
| Transition from ⁴ F _{3/2} | Wavelength (nm) | $A_{rad}(s^{-1})$ | $\beta_{exp}(\%)$ | τ _{cal} (μs) |
| ⁴ _{13/2} | 1332 | 1223.58 | 5.91774 | 441.274 |
| ⁴ _{11/2} | 1048 | 908.478 | 40.0888 | |
| 4 _{9/2} | 865 | 134.106 | 53.9935 | |

^a Based on emission data from K₅NdLi₂F₁₀ nanocrystals dispersion in PEG400.

In this work, a lifetime of 174.6 μ s was measured for the ${}^{4}F_{3/2} \rightarrow {}^{4}I_{11/2}$ transition of K₅NdLi₂F₁₀ nanocrystals dispersion in PEG-400 that was confirmed by the radiative lifetime and the fluorescence branching ratios of ${}^{4}F_{3/2} \rightarrow {}^{4}I_{11/2}$ transition. According to the function (5), the emission quantum yield is deduced to be as high as 39.57 %.

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